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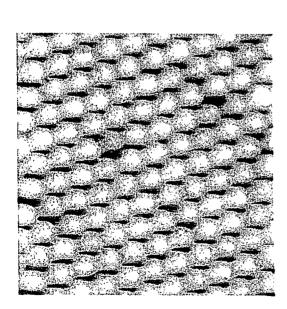
- (71) Applicant (for all designated States except US): LOCK HAVEN UNIVERSITY OF PENNSYLVANIA OF THE STATE SYSTEM OF HIGHER EDUCATION [US/US]; 401 North Fairview Street, Lock Haven, PA 17745 (US).
- (72) Inventor (for US only): JIA, Dongdong, X.; 408 West Church Street, Lock Haven, PA 17745 (US).
- (72) Inventor: GOONEWARDENE, Anura; 34 Curtis Circle, Mill Hall, PA 17751 (US).
- (74) Agent: QUINN, Charles, N.; Fox Rothschild Llp, 2000 Market Street, 10th Floor, Philadelphia, PA 19103 (US).

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(57) Abstract: Nanorings and methods for fabrication thereof, preferably of gold and tungsten, involve deposition on silicon wafer and/or glass substrates using random incidence sputtering deposition and thermal vapor deposition techniques to produce two dimensional tungsten nanotriangle and gold nanoring arrays on the silicon wafer substrates with the size of resulting equilateral tungsten nanotriangles being about 100 nm per side and being spaced about 210 nm from each other, and with the gold nanorings being about 220 nm in diameter, 40 nm wide, 10 nm thick and being spaced about 560 nm from each other.

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PCT/US2006/049163 A. CLASSIFICATION OF SUBJECT MATTER INV. C23C14/04 C23C1 C23C14/04 C23C14/22 According to International Patent Classification (IPC) or to both national classification and IPC **B. FIELDS SEARCHED** Minimum documentation searched (classification system followed by classification symbols) C23C Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched Electronic data base consulted during the international search (name of data base and, where practical, search terms used) EPO-Internal, COMPENDEX C. DOCUMENTS CONSIDERED TO BE RELEVANT Citation of document, with indication, where appropriate, of the relevant passages Category\* Relevant to claim No. Υ DATABASE COMPENDEX [Online] 1 - 48ENGINEERING INFORMATION, INC., NEW YORK, NY, US; 4 November 2005 (2005-11-04), LI QIMING ET AL: "Formation of epitaxial Ge nanorings on Si by self-assembled Sio2 particles and touchdown of Ge through a thin layer of Sio2" XP002474316 Database accession no. E2006159816196 abstract X Further documents are listed in the continuation of Box C See patent family annex. Special categories of cited documents: "T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the "A" document defining the general state of the art which is not considered to be of particular relevance invention earlier document but published on or after the international "X" document of particular relevance; the claimed invention filing date cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone \*L\* document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such docudocument referring to an oral disclosure, use, exhibition or ments, such combination being obvious to a person skilled document published prior to the international filing date but later than the priority date claimed "&" document member of the same patent family Date of the actual completion of the international search Date of mailing of the international search report 4 April 2008: 18/04/2008 Name and mailing address of the ISA/ Authorized officer European Patent Office, P.B. 5818 Patentlaan 2 NL - 2280 HV Rijswijk Tel. (+31-70) 340-2040, Tx. 31 651 epo nl, Fax: (+31-70) 340-3016 Ekhult, Hans

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